



浙江世菱半导体有限公司  
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

## 产品规格书

### Specifcation of products

产品名称：单相整流桥模块

产品型号：MDQ75A-T11

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ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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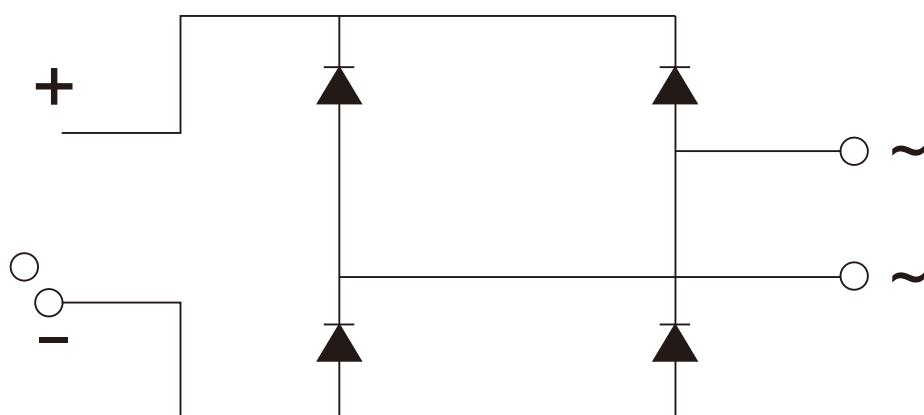
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拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j$ (°C)	VALUE			UNIT
				Min	Type	Max	
$I_o$	DC output current	Three-phase full wave rectifying circuit, $T_c=100$ °C	150			75	A
$V_{RRM}$	Repetitive peak reverse voltage	$V_{RRM}$ tp=10ms $V_{RsM}= V_{DRM} \& V_{RRM}+200V$	150	600		2200	V
$I_{RRM}$	Repetitive peak current	at $V_{RRM}$	150			6	mA
$I_{FSM}$	Surge forward current	10ms half sine wave	150			0.63	KA
$I^2t$	$I^2T$ for fusing coordination	$V_R=0.6V_{RRM}$				1.7	$A^2s*10^3$
$V_{FO}$	Threshold voltage		150			0.80	V
$r_F$	Forward slop resistance					9.8	mΩ
$V_{FM}$	Peak forward voltage	$I_{FM}=75A$	25			1.1	V
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	Single side cooled				0.75	°C /W
$V_{iso}$	Isolation voltage	50Hz, RM. S, t=1min, $I_{iso}$ : 1mA (max)	2500				V
$F_m$	Terminal connection torque						N.m
	Mounting torque( M6)					5.0	N.m
$T_{Stg}$	Stored temperature			-40		125	°C
$W_t$	Weight					108	g
Outline							

## OUTLINE DRAWING & CIRCUIT DIAGRAM



## Rating and Characteristic

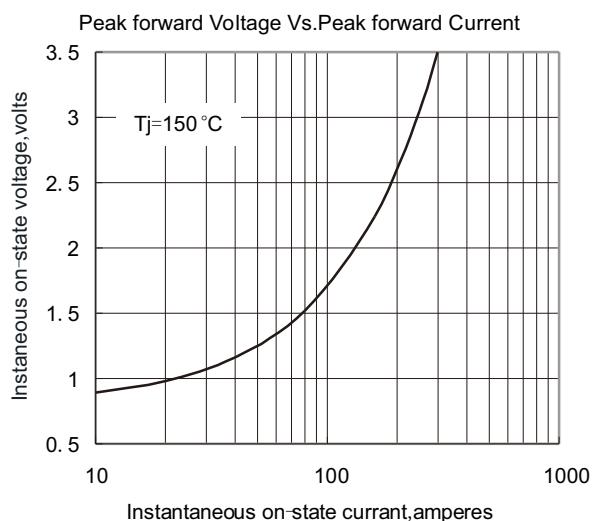


Fig. 1

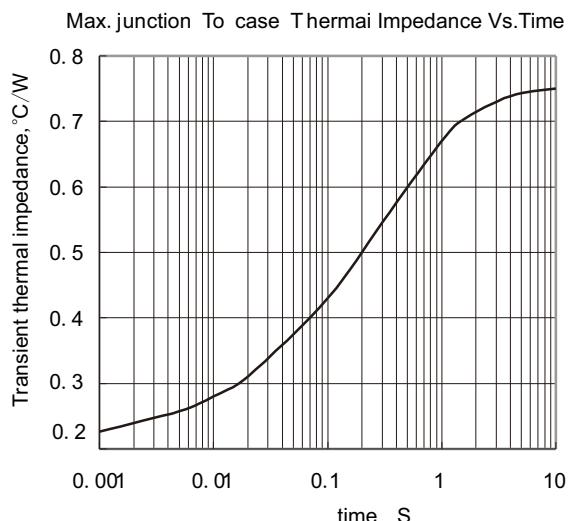


Fig. 2

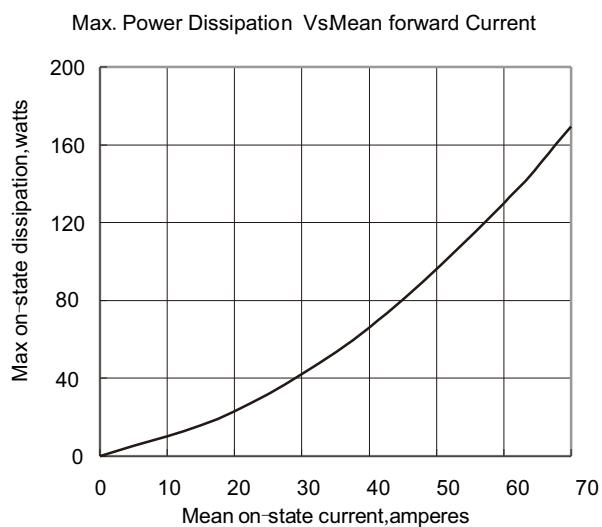


Fig. 3

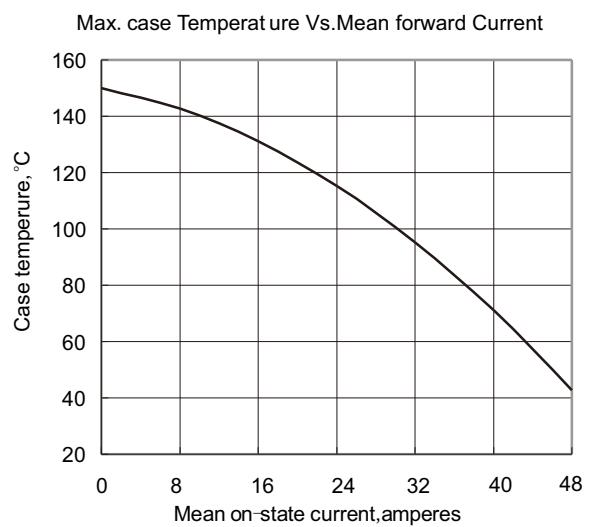


Fig. 4

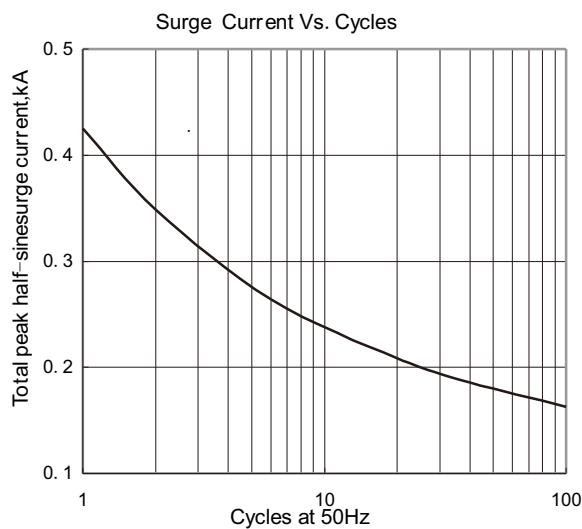


Fig. 5

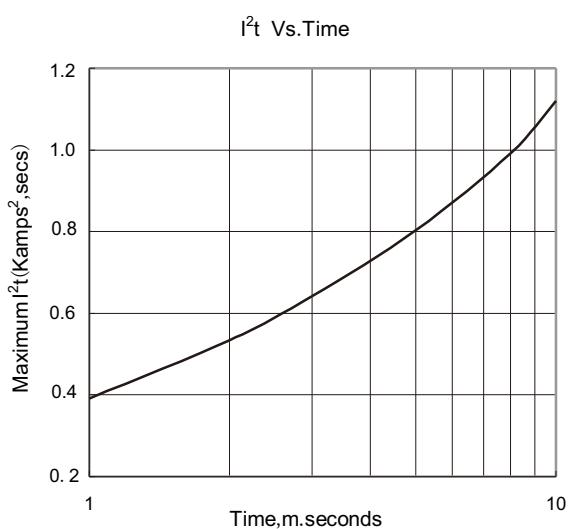


Fig. 6

## Outside Dimension

